NSN 5961-01-359-9643

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-9643 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.200 inches **Overall Diameter:** Between 0.115 inches and 0.180 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 660.0 breakdown voltage, dc and 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 100.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** 6.0 in. Long insulated wire leads with lugs **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No